COMPLIANT

HALOGEN FREE

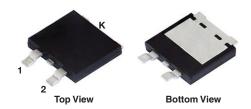


# Vishay General Semiconductor

# Dual Low-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.42 \text{ V}$  at  $I_F = 2.5 \text{ A}$ 

# eSMP<sup>®</sup> Series SMPD (TO-263AC)





#### **DESIGN SUPPORT TOOLS AVAILABLE**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 5 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	80 A			
$V_F$ at $I_F = 5$ A $(T_A = 125  ^{\circ}\text{C})$	0.52 V			
T <sub>J</sub> max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Circuit configuration Common cathode			

### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- · Ideal for automated placement
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

## **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V10DM60C	UNIT	
Device marking code			V10DM60C		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub> <sup>(1)</sup>	10	Α	
	per diode		5	A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	80	А	
Operating junction temperature range		T <sub>J</sub> <sup>(2)</sup>	-40 to +175	°C	
Storage temperature range		T <sub>STG</sub>	-55 to +175		

#### Notes

<sup>(1)</sup> Mounted on infinite heatsink

 $<sup>^{(2)}</sup>$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,JA}$ 



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.52	-	V
	I <sub>F</sub> = 5 A			0.58	0.66	
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C		0.42	-	
	I <sub>F</sub> = 5 A			0.52	0.60	
Reverse current at rated V <sub>R</sub> per diode	$V_R = 60 \text{ V}$ $T_A = 25 \text{ °C}$ $T_A = 125 \text{ °C}$	I <sub>R</sub> <sup>(2)</sup>	-	0.25	mA	
		T <sub>A</sub> = 125 °C	IR (=)	1.2	7	111/4
Typical junction capacitance	4.0 V, 1 MHz		CJ	570	-	pF

### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: Pulse width  $\leq 5 \text{ ms}$ 

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V10DM60C	UNIT	
Typical thermal resistance per device	$R_{\theta JC}^{(1)}$	2.5	°C/W	
	R <sub>0</sub> JA (2)(3)	58	C/VV	

### Notes

(1) Mounted on infinite heatsink

 $^{(2)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$  - junction-to-ambient

(3) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V10DM60C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V10DM60CHM3/I (1)	0.55	I	2000/reel	13" diameter plastic tape and reel		

### Note

(1) AEC-Q101 qualified

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# **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

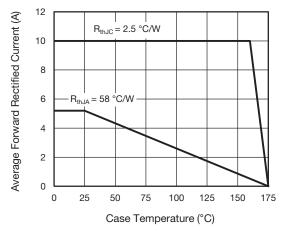
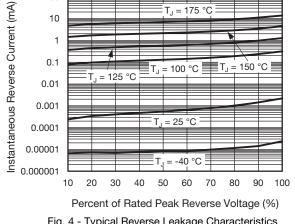


Fig. 1 - Maximum Forward Current Derating Curve



100

Fig. 4 - Typical Reverse Leakage Characteristics

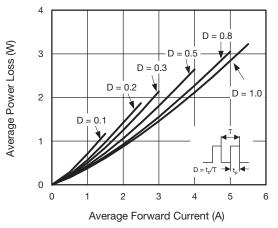


Fig. 2 - Average Power Loss Characteristics

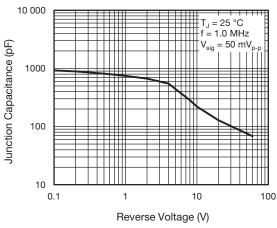
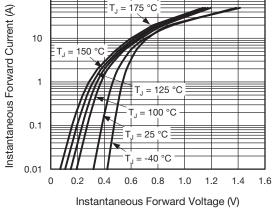


Fig. 5 - Typical Junction Capacitance



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Fig. 3 - Typical Instantaneous Forward Characteristics

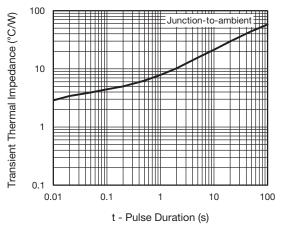


Fig. 6 - Typical Transient Thermal Impedance



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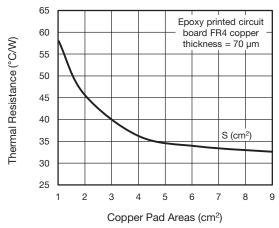
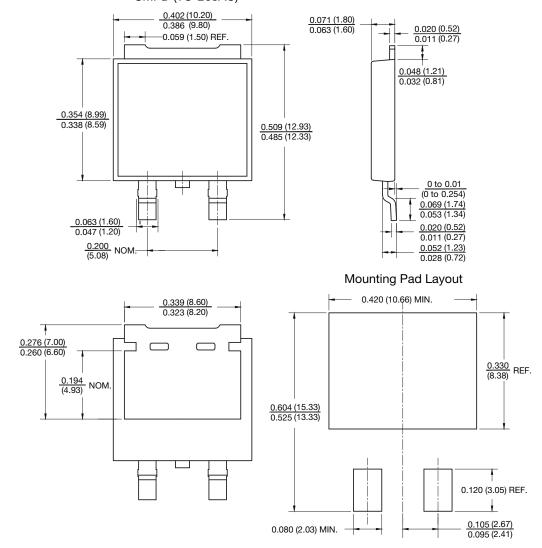


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters) SMPD (TO-263AC)





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